LME49725 PowerWise® Dual High Performance, High Fidelity Audio Operational Amplifier

Check for Samples: LME49725

FEATURES

- **Optimized for superior audio signal fidelity**
- **Output short circuit protection**
- **PSRR and CMRR exceed 120dB (typ)**

APPLICATIONS

- **Audio amplification**
- **Preamplifiers**
- **Multimedia**
- **Phono preamplifiers**
- **Professional audio**
- **Equalization and crossover networks**
- **Line drivers**
- **Line receivers**
- **Active filters**

DESCRIPTION

The LME49725 is part of the ultra-low distortion, low noise, high slew rate operational amplifier series optimized and fully specified for high performance, high fidelity applications. Combining advanced leading-edge process technology with state-of-the-art circuit design, the LME49725 audio operational amplifiers deliver superior audio signal amplification for outstanding audio performance. The LME49725 combines extremely low voltage noise density (3.3nV/$\sqrt{Hz}$) with vanishingly low THD+N (0.00004%) to easily satisfy the most demanding audio applications. To ensure that the most challenging loads are driven without compromise, the LME49725 has a high slew rate of ±15V/µs and an output current capability of ±22mA. Further, dynamic range is maximized by an output stage that drives 2kΩ loads to within 1V of either power supply voltage and to within 1.4V when driving 600Ω loads.

Part of the PowerWise® family of energy efficient solutions, the LME49725 consumes only 3.0mA of supply current per amplifier while providing superior performance to high performance, high fidelity applications.

The LME49725's outstanding CMRR (120dB), PSRR (120dB), and V_{OS} (0.5mV) give the amplifier excellent operational amplifier DC performance.

The LME49725 has a wide supply range of ±4.5V to ±18V. Over this supply range the LME49725's input circuitry maintains excellent common-mode and power supply rejection, as well as maintaining its low input bias current. The LME49725 is unity gain stable. This audio operational amplifier achieves outstanding AC performance while driving complex loads with values as high as 100pF.

The LME49725 is available in 8–lead narrow body SOIC.

Table 1. Key Specifications

	VALUE	UNIT
Power Supply Voltage Range	±4.5V to ±18	V
THD+N (A_V = 1, V_{OUT} = 3V_{RMS}, f_{IN} = 1kHz)		
R_L = 2kΩ	0.00004	% (typ)
R_L = 600Ω	0.00004	% (typ)
Quiescent current per Amplifier	3.0	mA (typ)
Input Noise Density	3.3	nV/$\sqrt{Hz}$ (typ)
Slew Rate	±15	V/µs (typ)
Gain Bandwidth Product	40	MHz (typ)
Open Loop Gain (R_L = 600Ω)	135	dB (typ)

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

All trademarks are the property of their respective owners.

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of the Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

Copyright © 2008, Texas Instruments Incorporated

Table 1. Key Specifications (continued)

	VALUE	UNIT
Input Bias Current	15	nA (typ)
Input Offset Voltage	0.5	mV (typ)
DC Gain Linearity Error	0.000009	% (typ)

Connection Diagram

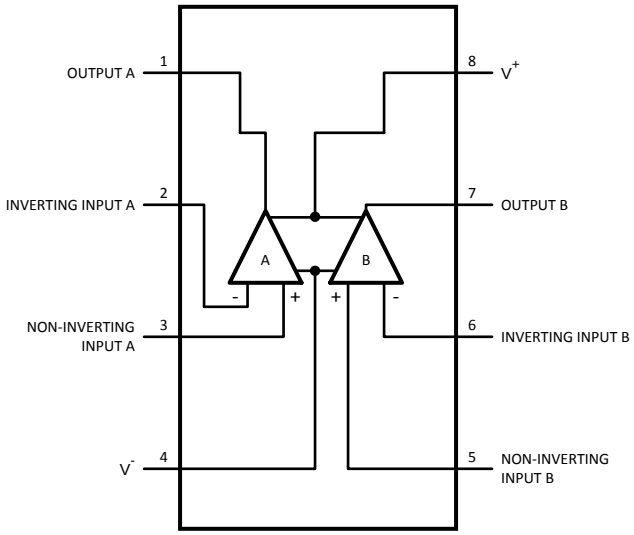


Figure 1. Dual-In-Line Package

N — National logo
Z — Assembly plant code
X — 1 Digit date code
TT — Die traceability
L49725 — LME49725
MA — Package code

Figure 2. LME49725 Top Mark

These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Copyright © 2008, Texas Instruments Incorporated

Absolute Maximum Ratings (1)

Power Supply Voltage ($V_S = V^+ - V^-$)	38V
Storage Temperature	−65°C to 150°C
Input Voltage	(V-)-0.7V to (V+)+0.7V
Differential Input Voltage	±0.7V
Output Short Circuit(2)	Continuous
Power Dissipation	Internally Limited
ESD Rating(3)	2000V
ESD Rating(4)	
Pins 1, 4, 7 and 8	200V
Pins 2, 3, 5 and 6	100V
Junction Temperature	150°C
Thermal Resistance	
θ_{JA} (SO)	145°C/W
Temperature Range	
$T_{MIN} \le T_A \le T_{MAX}$	–40°C ≤ T_A ≤ 85°C
Supply Voltage Range	±4.5V ≤ V_S ≤ ±18V

(1) "*Absolute Maximum Ratings*" indicate limits beyond which damage to the device may occur, including inoperability and degradation of device reliability and/or performance. Functional operation of the device and/or non-degradation at the *Absolute Maximum Ratings* or other conditions beyond those indicated in the *Recommended Operating Conditions* is not implied. The *Recommended Operating Conditions* indicate conditions at which the device is functional and the device should not be operated beyond such conditions. All voltages are measured with respect to the ground pin, unless otherwise specified.

(2) The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX}, θ_{JA}, and the ambient temperature, T_A. The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A) / \theta_{JA}$ or the number given in *Absolute Maximum Ratings*, whichever is lower.

(3) Human body model, applicable std. JESD22-A114C.

(4) Machine model, applicable std. JESD22-A115-A.

Copyright © 2008, Texas Instruments Incorporated

Electrical Characteristics for the LME49725 (1)

The specifications apply for V_S = ±15V, R_L = 2kΩ, f_{IN} = 1kHz, T_A = 25°C, unless otherwise specified.

Symbol	Parameter	Conditions	LME49725		Units (Limits)
			Typical (2)	Limit (3)	
THD+N	Total Harmonic Distortion + Noise	A_V = 1, V_{OUT} = 3V_{rms} R_L = 2kΩ R_L = 600Ω	 0.00004 0.00004	 0.0002	 % %
IMD	Intermodulation Distortion	A_V = 1, V_{OUT} = 3V_{RMS} Two-tone, 60Hz & 7kHz 4:1	0.00005		%
GBWP	Gain Bandwidth Product		40	30	MHz (min)
SR	Slew Rate		±15	±10	V/µs (min)
FPBW	Full Power Bandwidth	V_{OUT} = 1V_{P-P}, –3dB referenced to output magnitude at f = 1kHz	7		MHz
t_s	Settling time	A_V = –1, 10V step, C_L = 100pF 0.1% error range	1.6		µs
e_n	Equivalent Input Noise Voltage	f_{BW} = 20Hz to 20kHz	0.4	0.8	µV_{RMS} (max)
	Equivalent Input Noise Density	f = 1kHz f = 10Hz	3.3 20	5.2	nV/√Hz (max)
i_n	Current Noise Density	f = 1kHz f = 10Hz	1.4 3.5		pA/√Hz pA/√Hz
V_{OS}	Offset Voltage		±0.5	±1.0	mV (max)
$\Delta V_{OS}/\Delta Temp$	Average Input Offset Voltage Drift vs Temperature	–40°C ≤ T_A ≤ 85°C	0.2		µV/°C
PSRR	Average Input Offset Voltage Shift vs Power Supply Voltage	ΔV_S = 20V (4)	120	100	dB (min)
ISO_{CH-CH}	Channel-to-Channel Isolation	f_{IN} = 1kHz f_{IN} = 20kHz	118 112		dB dB
I_B	Input Bias Current	V_{CM} = 0V	±15	±90	nA (max)
$\Delta I_{OS}/\Delta Temp$	Input Bias Current Drift vs Temperature	–40°C ≤ T_A ≤ 85°C	0.1		nA/°C
I_{OS}	Input Offset Current	V_{CM} = 0V	11	65	nA (max)
V_{IN-CM}	Common-Mode Input Voltage Range		±13.9	(V+)-2.0 (V-)+2.0	V (min) V (min)
CMRR	Common-Mode Rejection	–10V<Vcm<10V	120	100	dB (min)
Z_{IN}	Differential Input Impedance		30		kΩ
	Common Mode Input Impedance	–10V<Vcm<10V	1000		MΩ
A_{VOL}	Open Loop Voltage Gain	–10V<Vout<10V, R_L = 600Ω	135	110	dB (min)
		–10V<Vout<10V, R_L = 2kΩ	135		dB
		–10V<Vout<10V, R_L = 10kΩ	135		dB
V_{OUTMAX}	Maximum Output Voltage Swing	R_L = 600Ω	±13.6	±11.5	V (min)
		R_L = 2kΩ	±13.9		V
		R_L = 10kΩ	±14.0		V
I_{OUT}	Output Current	R_L = 600Ω, V_S = ±17V	±22		mA (min)
I_{OUT-CC}	Instantaneous Short Circuit Current		+45 –35		mA mA

(1) The *Electrical Characteristics* tables list guaranteed specifications under the listed *Recommended Operating Conditions* except as otherwise modified or specified by the *Electrical Characteristics Conditions* and/or Notes. Typical specifications are estimations only and are not guaranteed.
(2) Typical values represent most likely parametric norms at T_A = +25ºC, and at the *Recommended Operation Conditions* at the time of product characterization and are not guaranteed.
(3) Datasheet min/max specification limits are guaranteed by test or statistical analysis.
(4) PSRR is measured as follows: V_{OS} is measured at two supply voltages, ±5V and ±15V, PSRR = |20log($\Delta V_{OS}/\Delta V_S$)|.

Copyright © 2008, Texas Instruments Incorporated

Electrical Characteristics for the LME49725 (1) (continued)

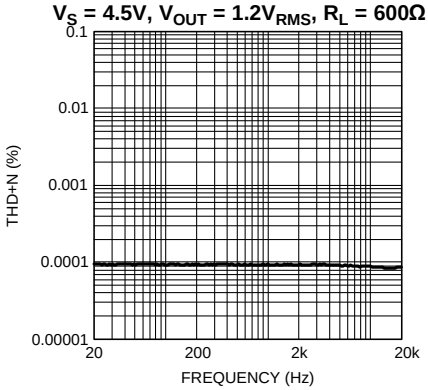
The specifications apply for V_S = ±15V, R_L = 2kΩ, f_{IN} = 1kHz, T_A = 25°C, unless otherwise specified.

Symbol	Parameter	Conditions	LME49725		Units (Limits)
			Typical (2)	Limit (3)	
R_{OUT}	Output Impedance	f_{IN} = 10kHz Closed-Loop Open-Loop	 0.01 18		 Ω Ω
C_{LOAD}	Capacitive Load Drive Overshoot	100pF	16		%
I_S	Quiescent Current per Amplifier	I_{OUT} = 0mA	3.0	4.5	mA (max)
f_C	1/f Corner Frequency		120		Hz

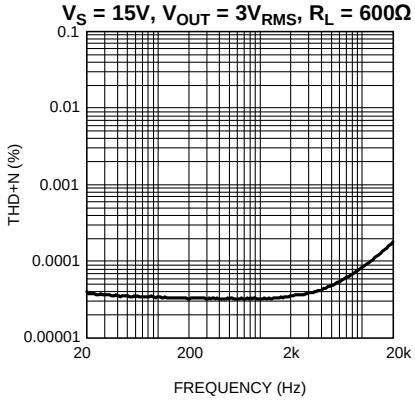
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics

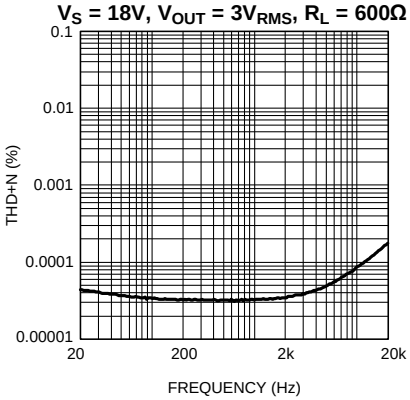
THD+N vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 600Ω



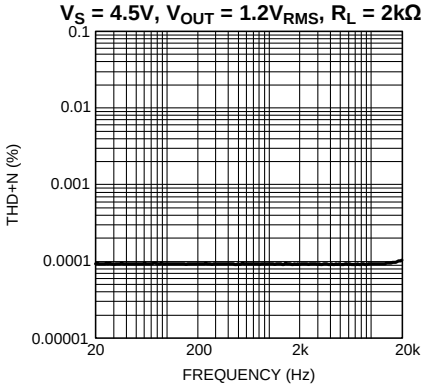
THD+N vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 600Ω



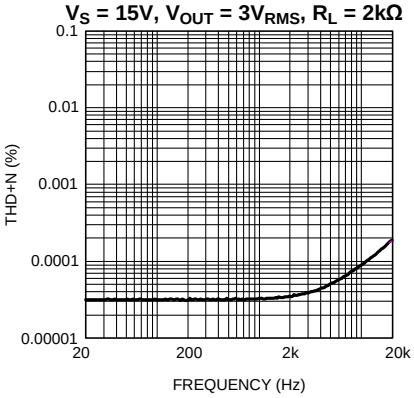
THD+N vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 600Ω



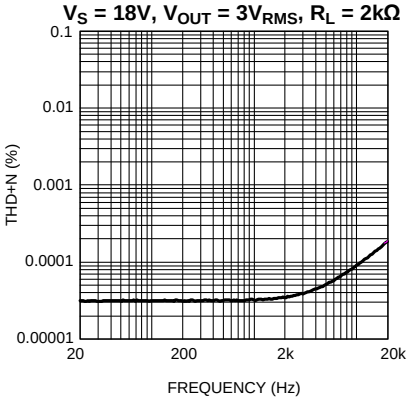
THD+N vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 2kΩ



THD+N vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 2kΩ



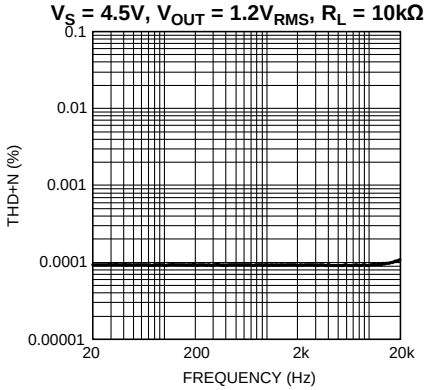
THD+N vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 2kΩ



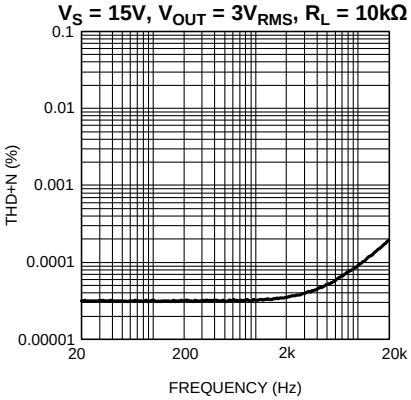
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

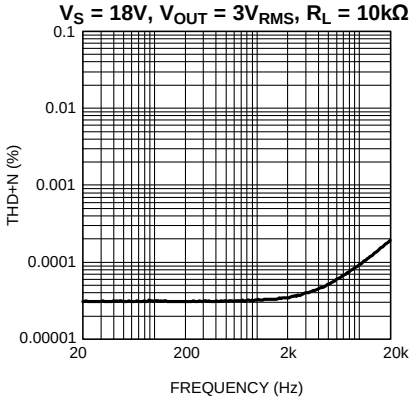
THD+N vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 10kΩ



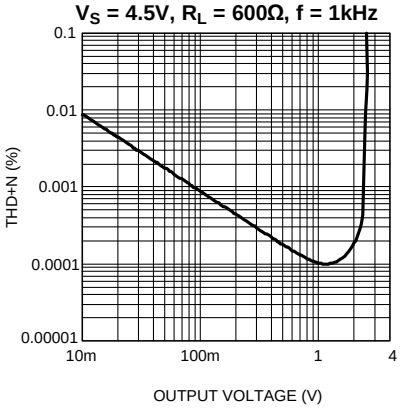
THD+N vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 10kΩ



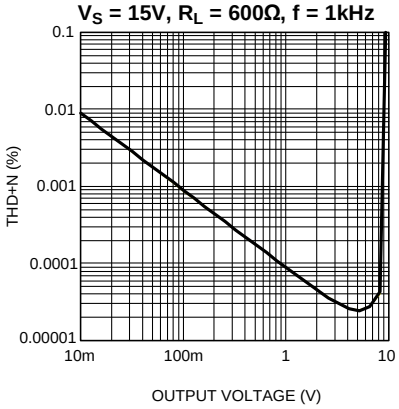
THD+N vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 10kΩ



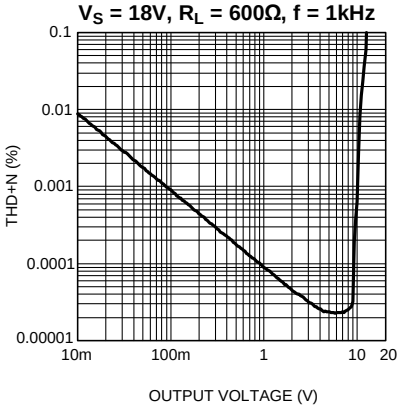
THD+N vs Output Voltage
V_S = 4.5V, R_L = 600Ω, f = 1kHz



THD+N vs Output Voltage
V_S = 15V, R_L = 600Ω, f = 1kHz



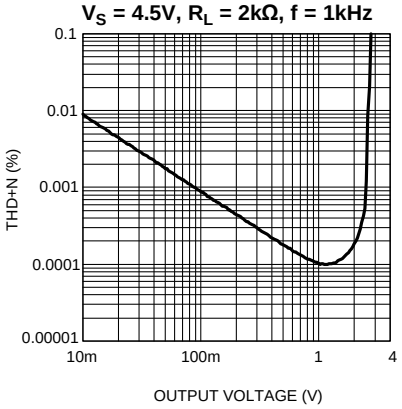
THD+N vs Output Voltage
V_S = 18V, R_L = 600Ω, f = 1kHz



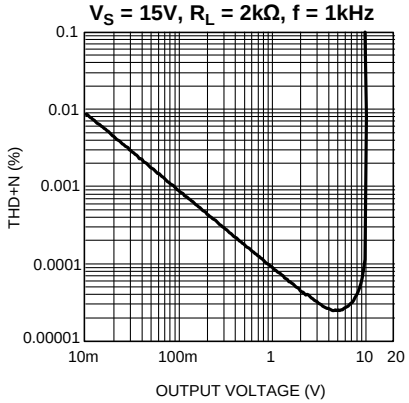
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

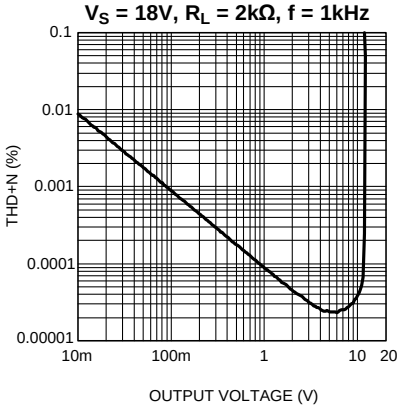
THD+N vs Output Voltage
V_S = 4.5V, R_L = 2kΩ, f = 1kHz



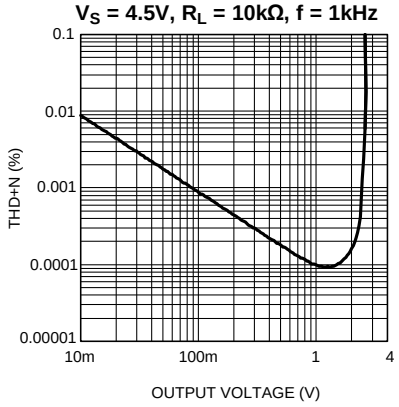
THD+N vs Output Voltage
V_S = 15V, R_L = 2kΩ, f = 1kHz



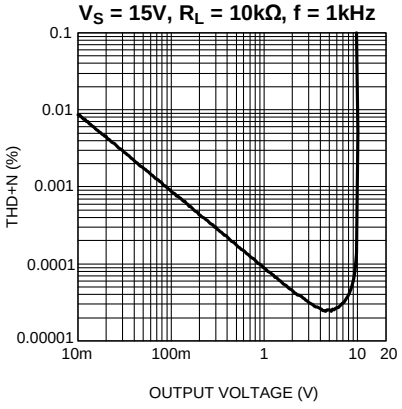
THD+N vs Output Voltage
V_S = 18V, R_L = 2kΩ, f = 1kHz



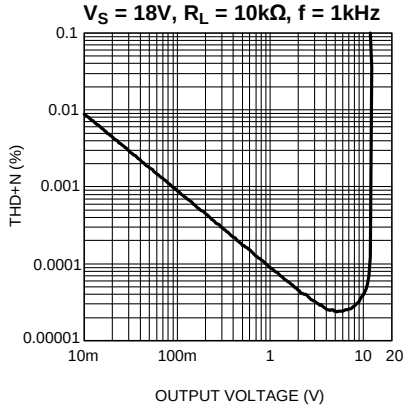
THD+N vs Output Voltage
V_S = 4.5V, R_L = 10kΩ, f = 1kHz



THD+N vs Output Voltage
V_S = 15V, R_L = 10kΩ, f = 1kHz



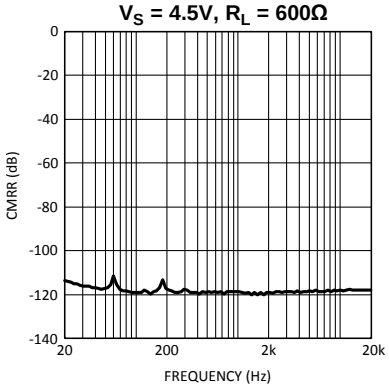
THD+N vs Output Voltage
V_S = 18V, R_L = 10kΩ, f = 1kHz



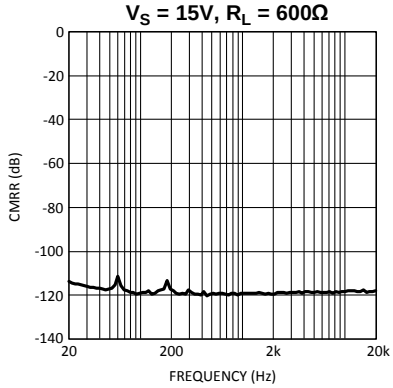
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

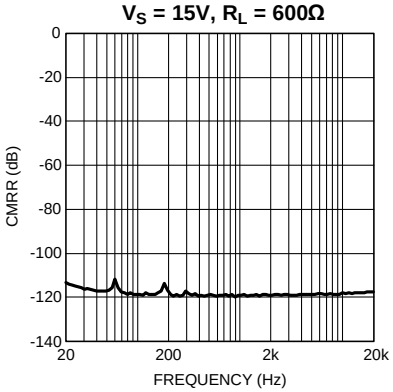
CMRR vs Frequency
V_S = 4.5V, R_L = 600Ω



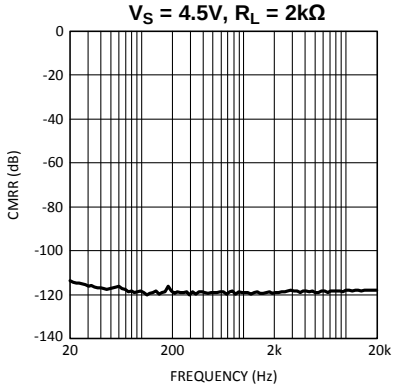
CMRR vs Frequency
V_S = 15V, R_L = 600Ω



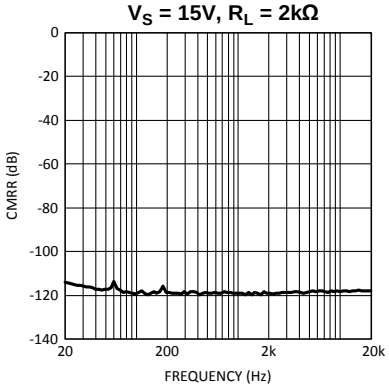
CMRR vs Frequency
V_S = 15V, R_L = 600Ω



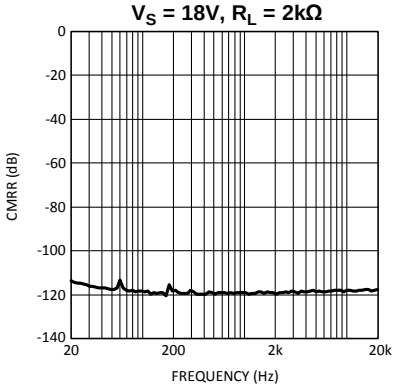
CMRR vs Frequency
V_S = 4.5V, R_L = 2kΩ



CMRR vs Frequency
V_S = 15V, R_L = 2kΩ



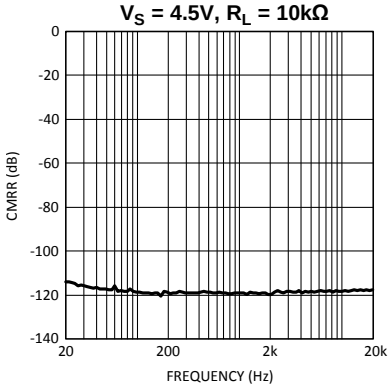
CMRR vs Frequency
V_S = 18V, R_L = 2kΩ



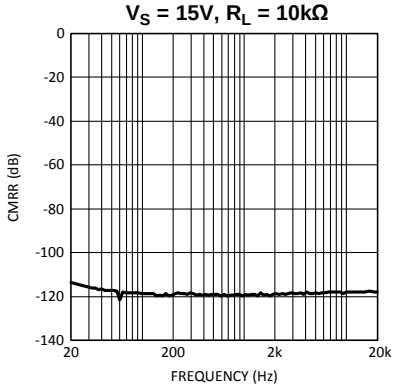
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

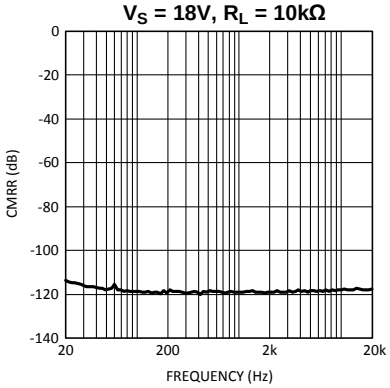
CMRR vs Frequency
V_S = 4.5V, R_L = 10kΩ



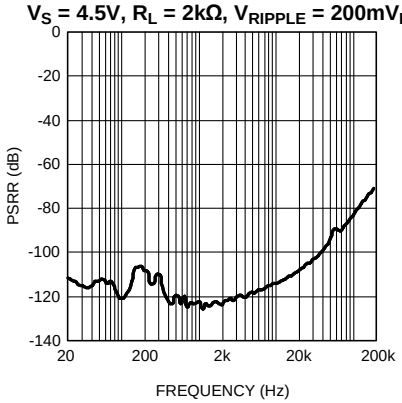
CMRR vs Frequency
V_S = 15V, R_L = 10kΩ



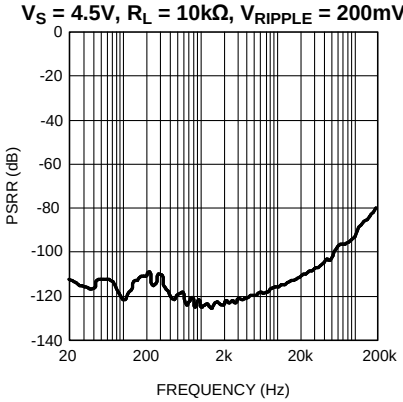
CMRR vs Frequency
V_S = 18V, R_L = 10kΩ



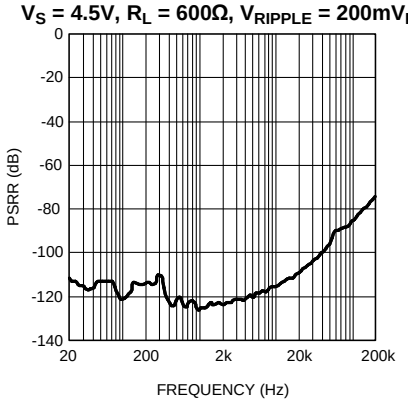
+PSRR vs Frequency
V_S = 4.5V, R_L = 2kΩ, V_{RIPPLE} = 200mV_{P-P}



+PSRR vs Frequency
V_S = 4.5V, R_L = 10kΩ, V_{RIPPLE} = 200mV_{P-P}



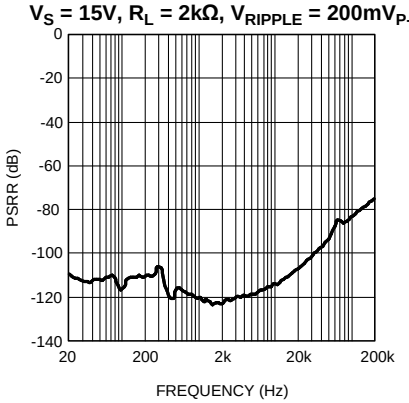
+PSRR vs Frequency
V_S = 4.5V, R_L = 600Ω, V_{RIPPLE} = 200mV_{P-P}



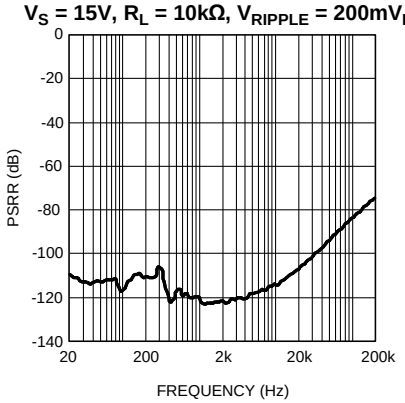
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

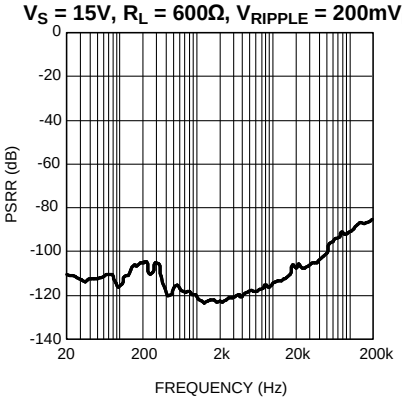
+PSRR vs Frequency
V_S = 15V, R_L = 2kΩ, V_{RIPPLE} = 200mV_{P-P}



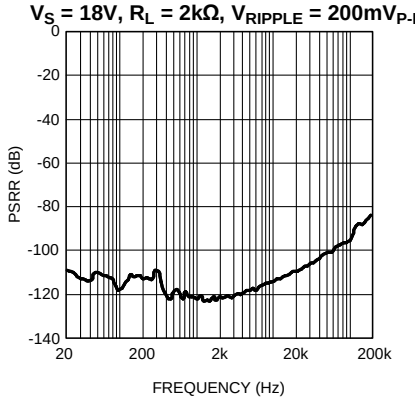
+PSRR vs Frequency
V_S = 15V, R_L = 10kΩ, V_{RIPPLE} = 200mV_{P-P}



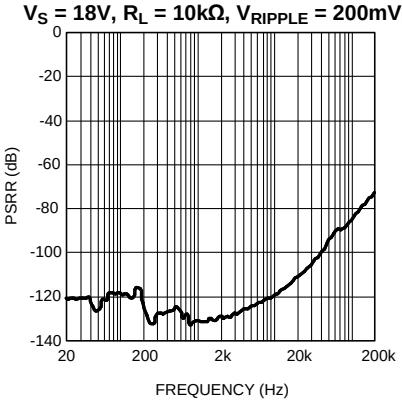
+PSRR vs Frequency
V_S = 15V, R_L = 600Ω, V_{RIPPLE} = 200mV_{P-P}



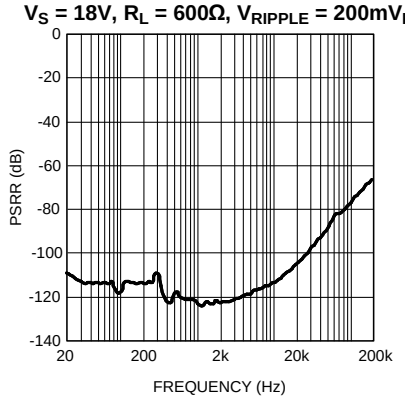
+PSRR vs Frequency
V_S = 18V, R_L = 2kΩ, V_{RIPPLE} = 200mV_{P-P}



+PSRR vs Frequency
V_S = 18V, R_L = 10kΩ, V_{RIPPLE} = 200mV_{P-P}



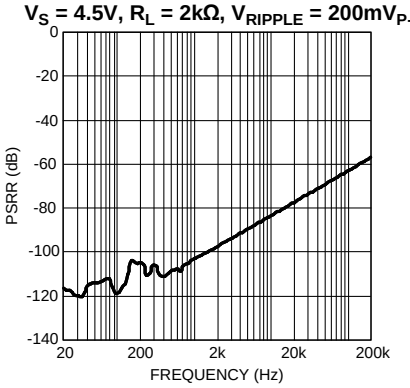
+PSRR vs Frequency
V_S = 18V, R_L = 600Ω, V_{RIPPLE} = 200mV_{P-P}



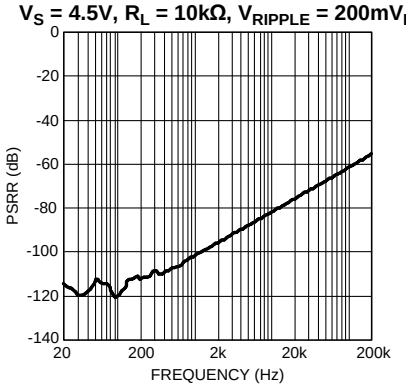
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

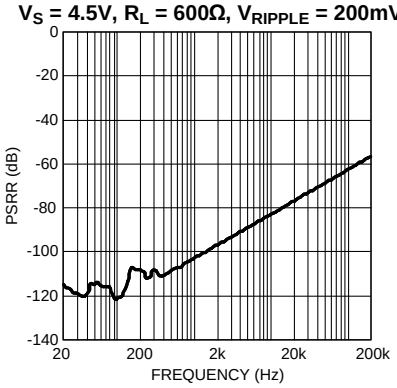
-PSRR vs Frequency
V_S = 4.5V, R_L = 2kΩ, V_{RIPPLE} = 200mV_{P-P}



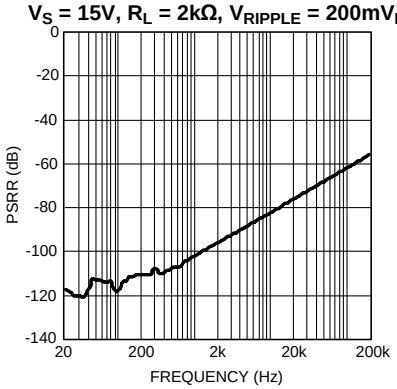
-PSRR vs Frequency
V_S = 4.5V, R_L = 10kΩ, V_{RIPPLE} = 200mV_{P-P}



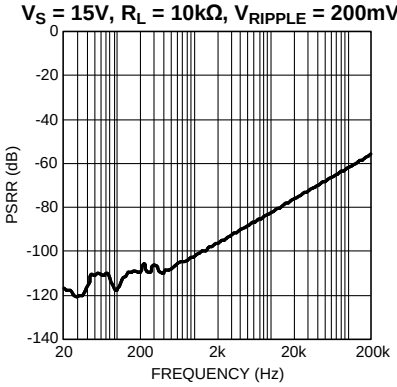
-PSRR vs Frequency
V_S = 4.5V, R_L = 600Ω, V_{RIPPLE} = 200mV_{P-P}



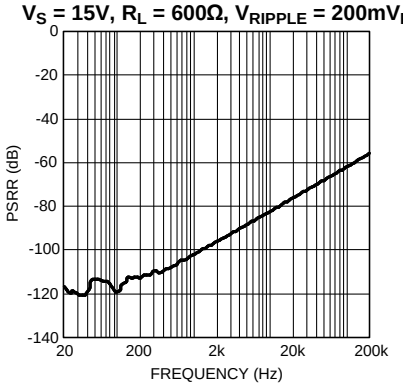
-PSRR vs Frequency
V_S = 15V, R_L = 2kΩ, V_{RIPPLE} = 200mV_{P-P}



-PSRR vs Frequency
V_S = 15V, R_L = 10kΩ, V_{RIPPLE} = 200mV_{P-P}



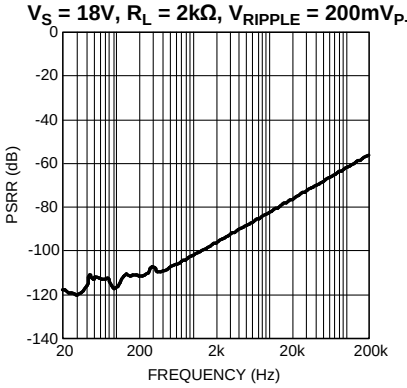
-PSRR vs Frequency
V_S = 15V, R_L = 600Ω, V_{RIPPLE} = 200mV_{P-P}



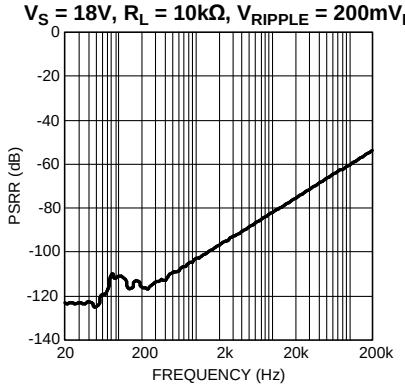
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

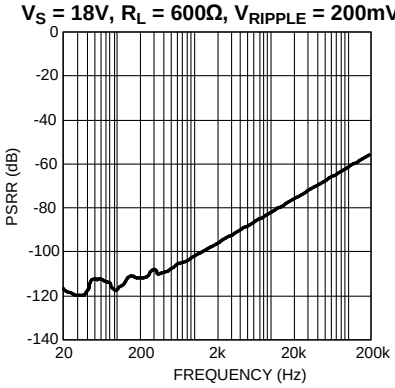
-PSRR vs Frequency
V_S = 18V, R_L = 2kΩ, V_{RIPPLE} = 200mV_{P-P}



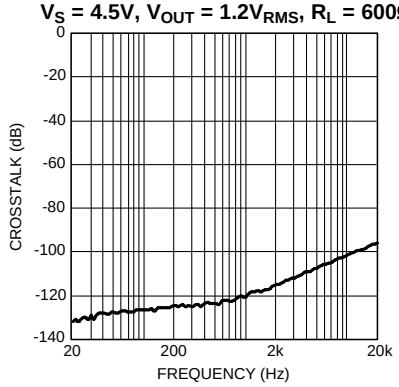
-PSRR vs Frequency
V_S = 18V, R_L = 10kΩ, V_{RIPPLE} = 200mV_{P-P}



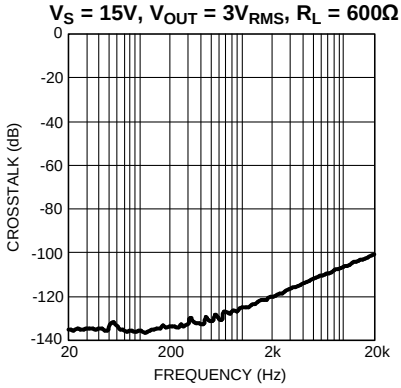
-PSRR vs Frequency
V_S = 18V, R_L = 600Ω, V_{RIPPLE} = 200mV_{P-P}



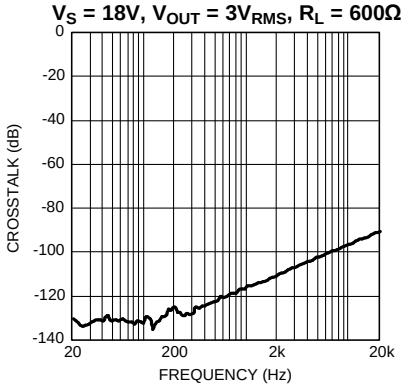
Crosstalk vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 600Ω



Crosstalk vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 600Ω



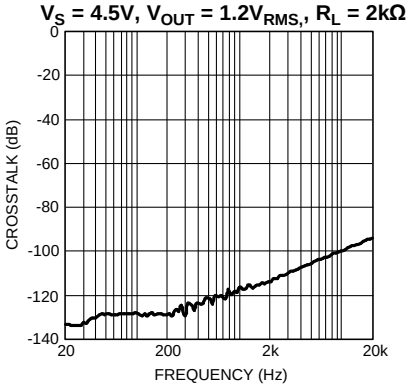
Crosstalk vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 600Ω



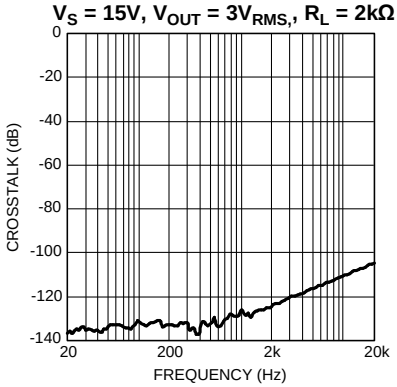
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

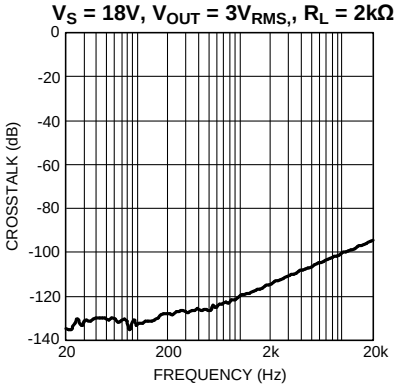
Crosstalk vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 2kΩ



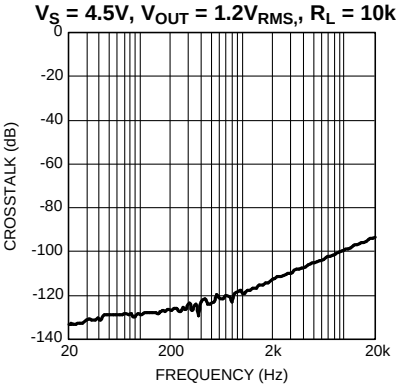
CrosstalkR vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 2kΩ



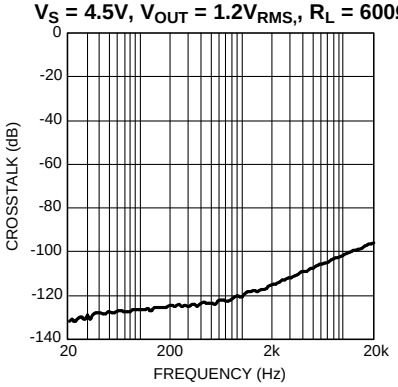
Crosstalk vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 2kΩ



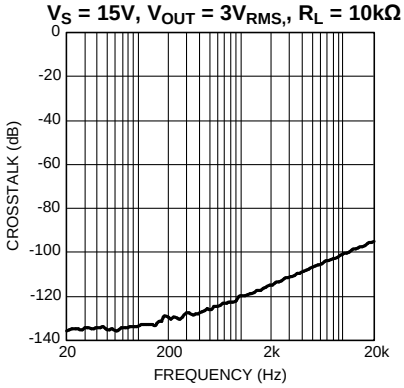
Crosstalk vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 10kΩ



Crosstalk vs Frequency
V_S = 4.5V, V_{OUT} = 1.2V_{RMS}, R_L = 600Ω



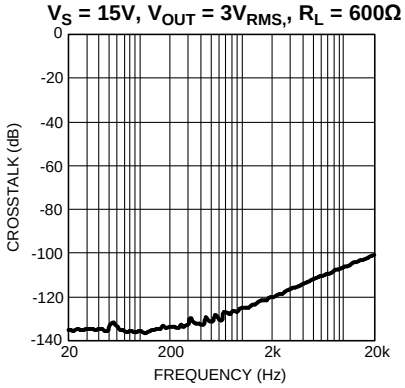
Crosstalk vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 10kΩ



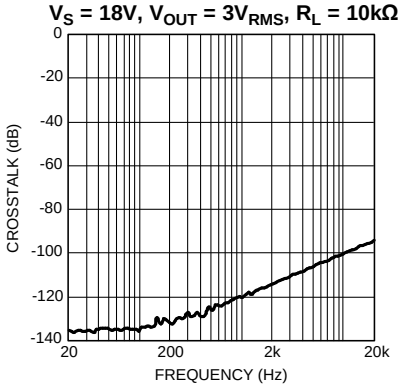
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

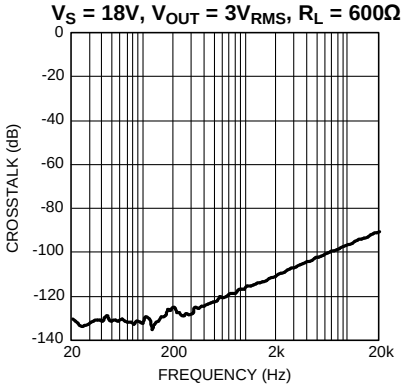
Crosstalk vs Frequency
V_S = 15V, V_{OUT} = 3V_{RMS}, R_L = 600Ω



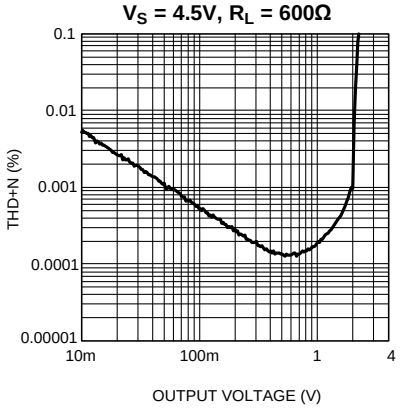
Crosstalk vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 10kΩ



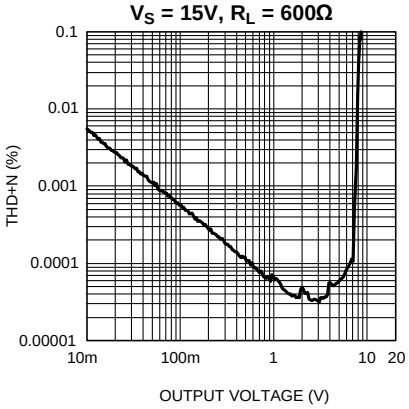
Crosstalk vs Frequency
V_S = 18V, V_{OUT} = 3V_{RMS}, R_L = 600Ω



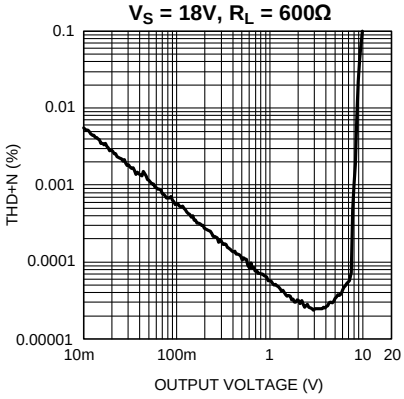
IMD vs Output Voltage
V_S = 4.5V, R_L = 600Ω



IMD vs Output Voltage
V_S = 15V, R_L = 600Ω



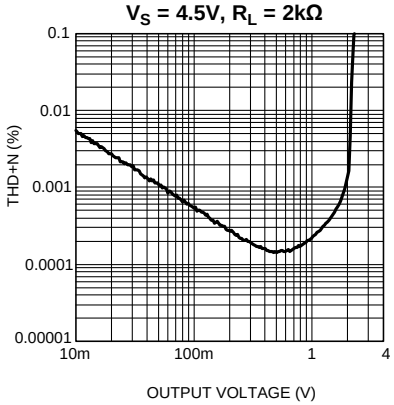
IMD vs Output Voltage
V_S = 18V, R_L = 600Ω



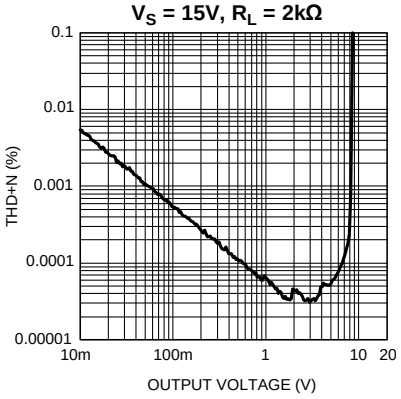
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

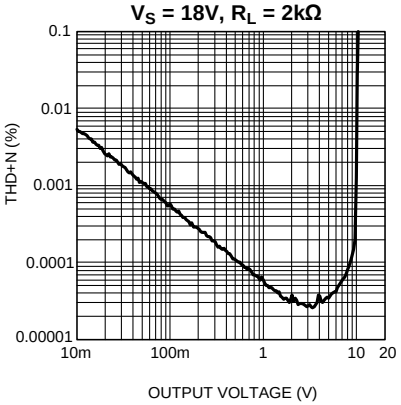
IMD vs Output Voltage
V_S = 4.5V, R_L = 2kΩ



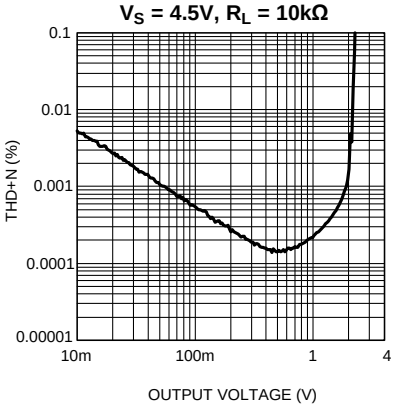
IMD vs Output Voltage
V_S = 15V, R_L = 2kΩ



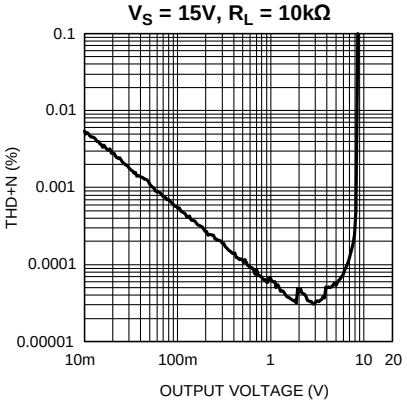
IMD vs Output Voltage
V_S = 18V, R_L = 2kΩ



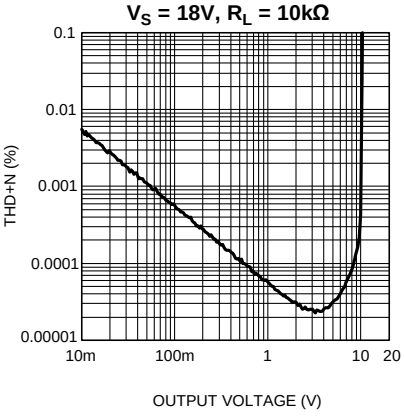
IMD vs Output Voltage
V_S = 4.5V, R_L = 10kΩ



IMD vs Output Voltage
V_S = 15V, R_L = 10kΩ



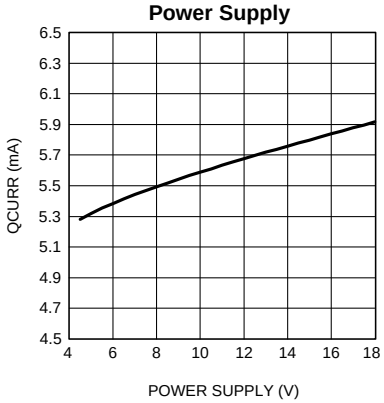
IMD vs Output Voltage
V_S = 18V, R_L = 10kΩ



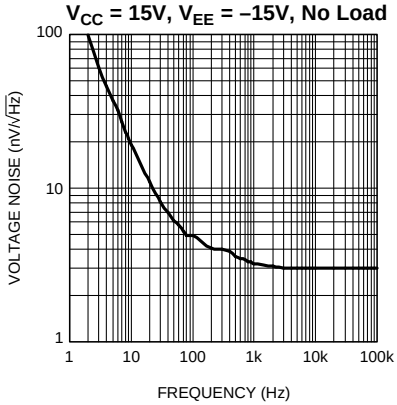
Copyright © 2008, Texas Instruments Incorporated

Typical Performance Characteristics (continued)

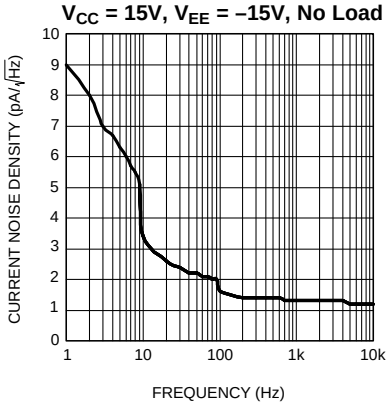
Total Quiescent Current vs Power Supply



Voltage Noise Density vs Frequency V_{CC} = 15V, V_{EE} = –15V, No Load



Current Noise vs Frequency V_{CC} = 15V, V_{EE} = –15V, No Load



Application Information

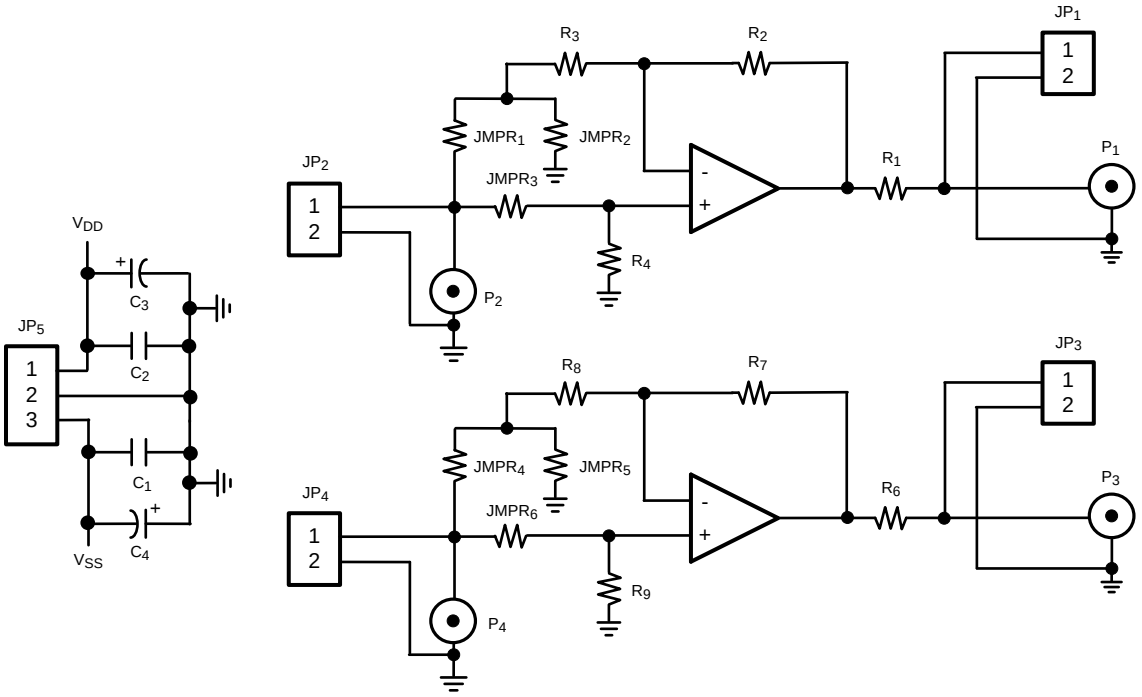
OPERATING RATINGS AND BASIC DESIGN GUIDELINES

The LME49725 has a supply voltage range from +9V to +36V single supply or ±4.5V to ±18V dual supply.

Bypass capacitors for the supplies should be placed as close to the amplifier as possible. This will help minimize any inductance between the power supply and the supply pins. In addition to a 10µF capacitor, a 0.1µF capacitor is also recommended.

The amplifier's inputs lead lengths should also be as short as possible. If the op amp does not have a bypass capacitor, it may oscillate.

Demonstration Board Schematic



Bill Of Materials For Demonstration Board (Inverting Configuration)

Description	Designator(1)	Part Number	Mfg
Ceramic Capacitor 0.1µF, 10% 50V 0805 SMD	C1, C2	C0805C104K3RAC7533	Kemet
Tantalum Capacitor 10µF, 10% 20V, B-size	C3, C4	T491B106K025AT	Kemet
Resistor 0Ω, 1/8W, 1% 0805 SMD	JMPR1, JMPR4, R1, R4, R6, R9	CRCW0805000020EA	Vishay
Resistor 10kΩ, 1/8W, 1% 0805 SMD	R2, R3, R8, R7	CRCW080510K0FKEA	Vishay
Header, 2-Pin	JP1, JP2, JP3, JP4		
Header, 3-Pin	JP5		
SMA stand-up connectors	P1-P4 (Optional)	132134	Amphenol COnnex

(1) Do not stuff JMPR2, JMPR3, JMPR5, and JMPR6.

Copyright © 2008, Texas Instruments Incorporated

Demonstration Board Layout

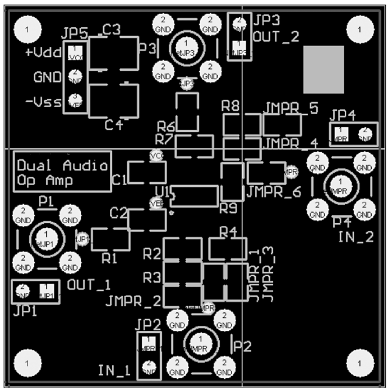


Figure 3. Silkscreen Layer

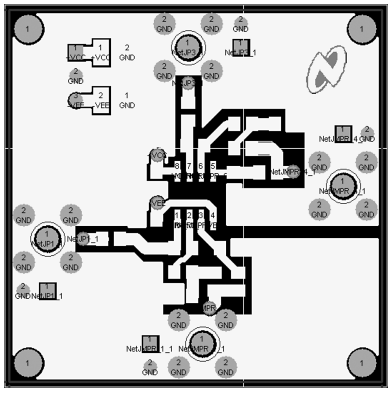


Figure 4. Top Layer

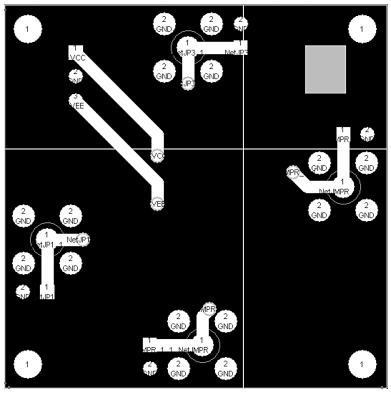


Figure 5. Bottom Layer

Revision History

Rev	Date	Description
1.0	04/03/08	Initial release.

Copyright © 2008, Texas Instruments Incorporated

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Samples (Requires Login)
LME49725MA/NOPB	ACTIVE	SOIC	D	8	95	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	
LME49725MAX/NOPB	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

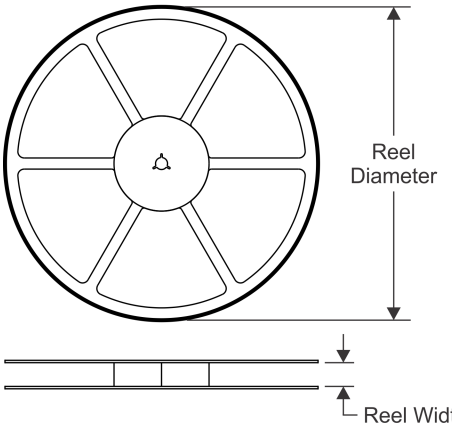
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

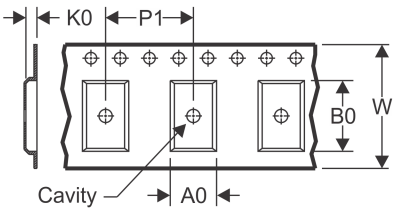
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

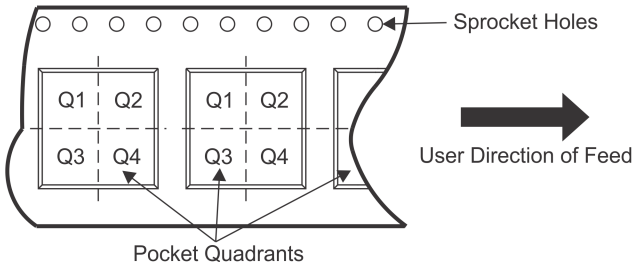


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

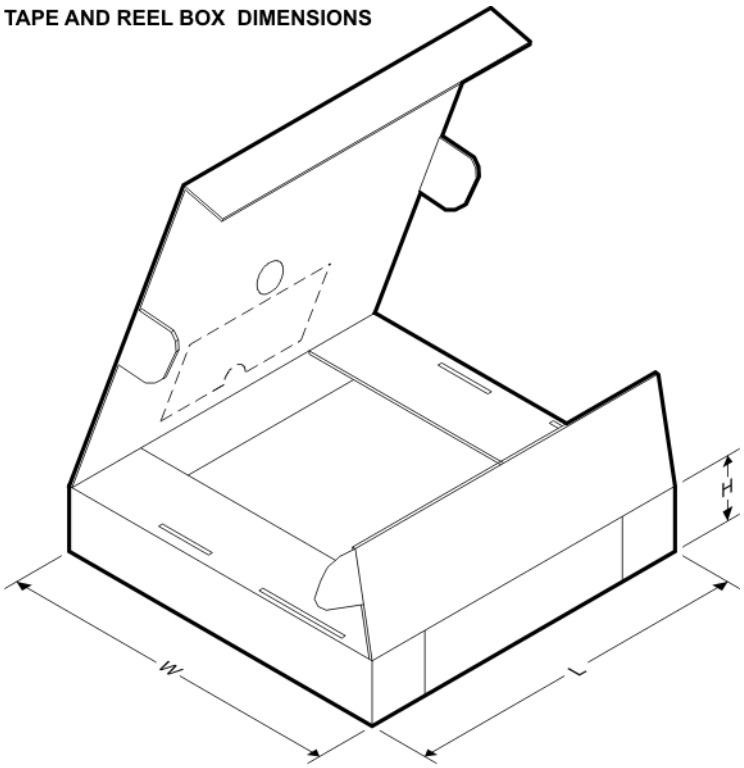
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LME49725MAX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1

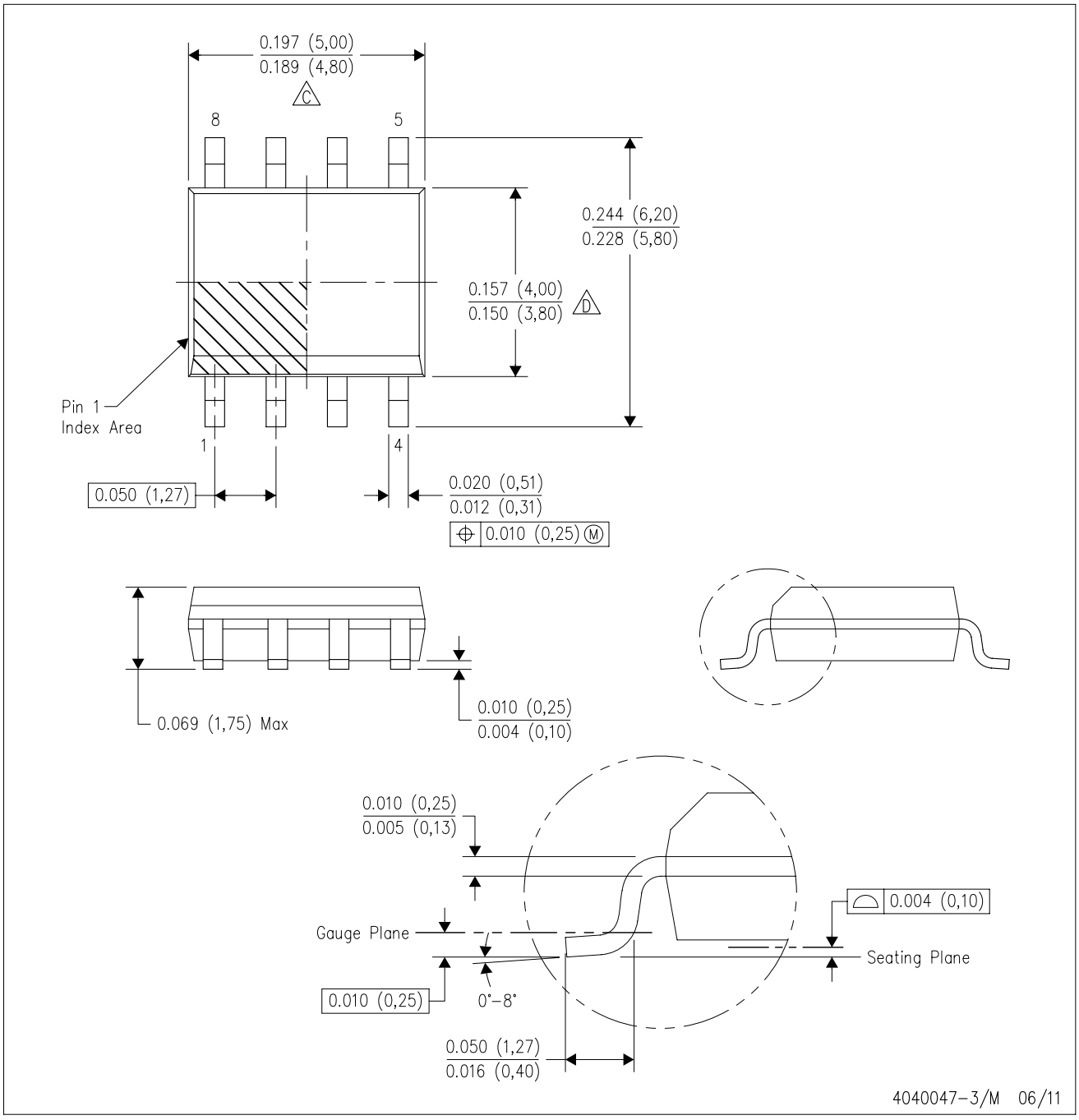
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LME49725MAX/NOPB	SOIC	D	8	2500	349.0	337.0	45.0

D (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
D. Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
E. Reference JEDEC MS–012 variation AA.

IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as “components”) are sold subject to TI’s terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI’s terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers’ products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers’ products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI’s goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or “enhanced plastic” are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have ***not*** been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		**Applications**	
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial
Interface	interface.ti.com	Medical	www.ti.com/medical
Logic	logic.ti.com	Security	www.ti.com/security
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video
RFID	www.ti-rfid.com		
OMAP Applications Processors	www.ti.com/omap	**TI E2E Community**	e2e.ti.com
Wireless Connectivity	www.ti.com/wirelessconnectivity		

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2012, Texas Instruments Incorporated